

FEATURES

- ± 6 mV ($\pm 0.5\%$) max. initial tolerance (A grade)
- Operating Current 10 μ A to 20mA
- Low Voltage Reference 1.240
- Max. 0.5 Ω Dynamic Impedance (A grade)
- Low Temperature Coefficient
- SOT-23 Package Available
- Low cost

APPLICATIONS

- Battery Powered Systems
- Instrumentation
- A/D, D/A Converters
- Temperature measurement
- Current sources
- Notebook/Personal Computer
- Monitors/ VCR/ TV
- Pagers

GENERAL DESCRIPTION

The AMS3100-1.2 are two-terminal micropower band-gap voltage reference that feature a very low dynamic impedance and good temperature coefficient, operating over a 10 μ A to 20mA current range. AMS3100-1.2 is trimmed at wafer test level to optimize the temperature coefficient and tight output voltage tolerance. The advanced process technology used, makes the AMS3100-1.2 exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation. The extremely low power drain, makes these reference diodes useful for micropower circuitry. These voltage references can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further more, the wide operating current allows it to replace older references with a tight tolerance part. Pin to pin compatible with other standard industry references, the AMS3100-1.2 offers the advantage of long term stability at low cost.

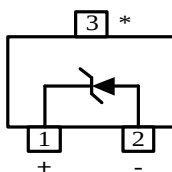
The AMS3100-1.2 is operating over a -40°C to 85°C temperature range and is available in the space saving SOT-23 package.

ORDERING INFORMATION:

TOL.	PACKAGE TYPE	OPERATING TEMPERATURE RANGE
	SOT-23	
± 6 mV	AMS3100-1.2AM	-40°C to 85°C
± 12 mV	AMS3100-1.2BM	-40°C to 85°C
± 25 mV	AMS3100-1.2CM	-40°C to 85°C

PIN CONNECTIONS

3L SOT-23
(M)



Top View

*This pin must be left floating or connected to pin 2

AMS3100-1.2

ABSOLUTE MAXIMUM RATINGS (Note 1)

Reverse Current	30mA	Lead Temperature	
Forward Current	10mA	Vapor phase (60 sec)	215°C
Operating Temperature Range	-40°C to 85°C	Infrared (15 sec.)	220°C
Storage temperature	-55°C to +150°C	Thermal Resistance (θ_{JA})	410°C/W

ELECTRICAL CHARACTERISTICS

Electrical Characteristics at $I_R = 100 \mu A$, and $T_A = +25^\circ C$ unless otherwise specified.

Parameter	Conditions	AMS3100A-1.2			AMS3100B-1.2			AMS3100C-1.2			Units
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Reverse Breakdown Voltage (Note 3)	$I_R = 100 \mu A$	1.229	1.235	1.241	1.223	1.235	1.249	1.210	1.235	1.260	V
Reverse Dynamic Impedance (Note 4)	$I_R = 100 \mu A$, $f = 20Hz$		0.2	0.50		0.5			0.5		Ω
Reverse Breakdown Voltage Change with current (Note 3)	$10 \mu A \leq I_R \leq 1mA$ $1mA \leq I_R \leq 20mA$		1.0 5				1.0 5			1.0 5	mV
Min. Operating Current (Note 3)			5	10 15		5	10 15		5	10 15	μA μA
Wide Band Noise (Note 4)	$I_R = 100 \mu A$, $10Hz \leq f \leq 10kHz$		60			60			60		μV
Temperature Coeff. (Note 5)			25	50		40	100		75		ppm/°C
Long Term Stability (Note 4)	$T_A = 25^\circ C \pm 1^\circ C$ $T = 1000 Hr$		20			20			20		ppm

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Parameters identified with **boldface type** apply at temperature extremes. All other numbers apply at $T_A = T_J = 25^\circ C$.

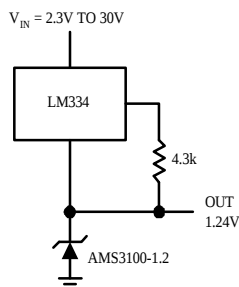
Note 3: Guaranteed and 100% production tested.

Note 4: Guaranteed but not 100% production tested. These limits are not used to calculate average outgoing quality levels.

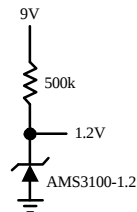
Note 5: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating T_{MAX} and T_{MIN} , divided by $T_{MAX} - T_{MIN}$. The measured temperatures are $0^\circ C$, $25^\circ C$, $85^\circ C$.

TYPICAL APPLICATIONS

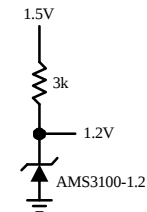
Wide Input
Range Reference



Micropower Reference
from 9V Battery

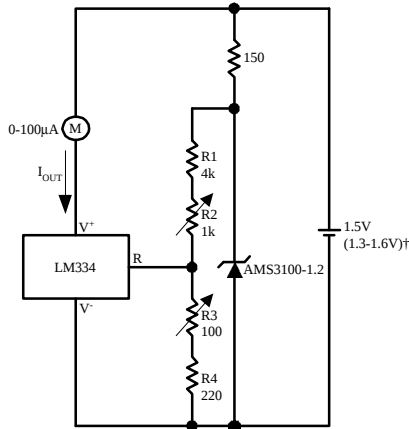


Reference from
1.5V Battery

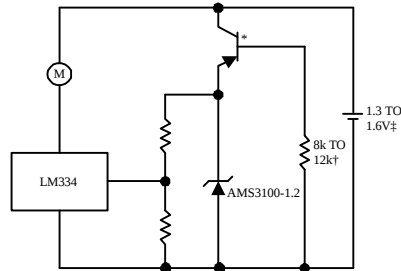


TYPICAL APPLICATIONS (Continued)

0°C - 100°C Thermometer

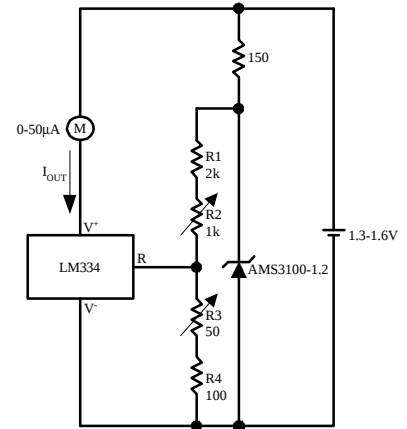


Lower Power Thermometer



* 2N3638 or 2N2907 select for inverse $H_{FE} \approx 5$
Select for operation at 1.3V
 $I_Q \approx 600\mu A$ to $900\mu A$

0°C - 100°C Thermometer



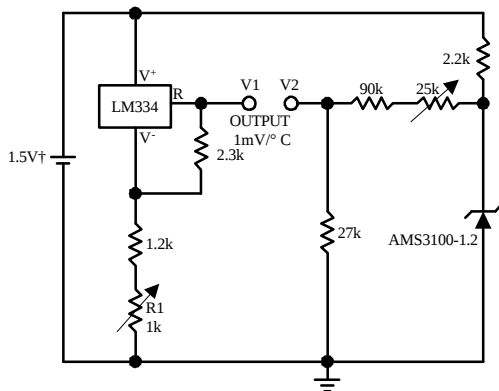
Calibration

1. Short AMS3100-1.2, adjust R3 for $I_{OUT} = \text{temp}$ at $1\mu A/^{\circ}K$
2. Remove short, adjust R2 for correct reading in $^{\circ}C$
 I_Q at 1.3V $\approx 500\mu A$
 I_Q at 1.6V $\approx 2.4mA$

Calibration

1. Short AMS3100-1.2, adjust R3 for $I_{OUT} = \text{temp}$ at $1.8\mu A/^{\circ}K$
2. Remove short, adjust R2 for correct reading in $^{\circ}F$

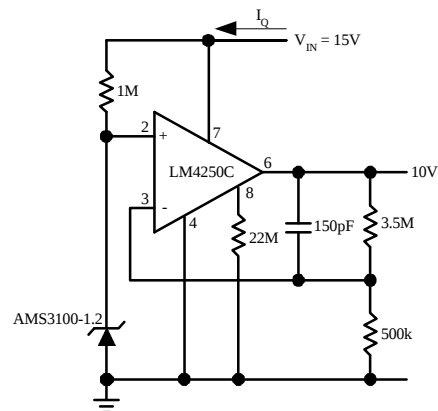
Centigrade Thermometer



Calibration

1. Adjust R1 so that $V1 = \text{temp}$ at $1mV/^{\circ}K$.
2. Adjust V2 to 273.2mV.
 I_Q for 1.3V to 1.6V battery voltage = $50\mu A$ to $150\mu A$

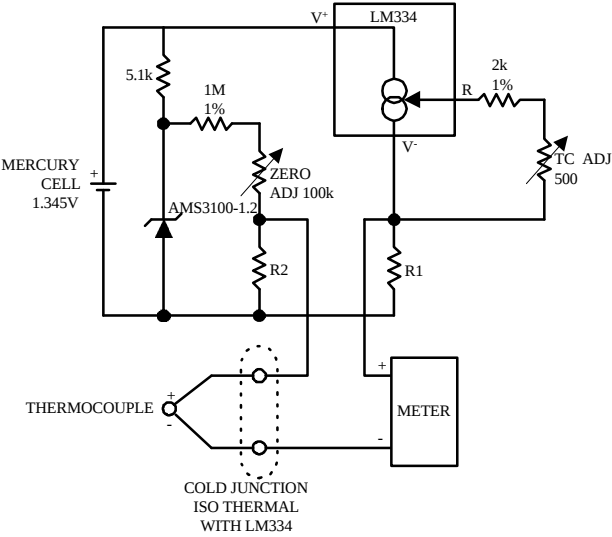
Micropower* 10V Reference



* $I_Q \approx 20\mu A$ standby current

TYPICAL APPLICATIONS (Continued)

Micropower Thermocouple Cold Junction Compensator



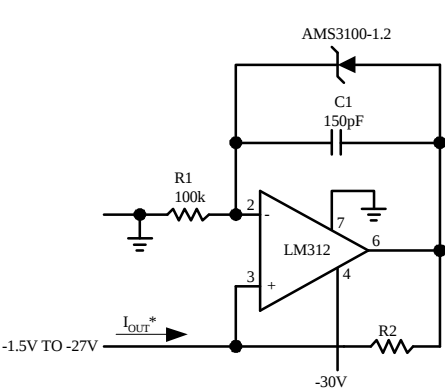
Adjustment Procedure

- 1. Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.
- 2. Adjust ZERO ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

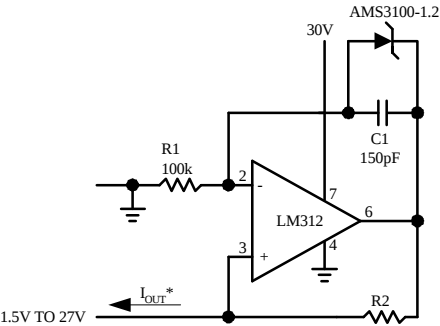
Thermocouple Type	Seebeck Coefficient (mV/ °C)	R1 (Ω)	R2 (Ω)	Voltage Across R1 @ 25°C (mV)	Voltage Across R2 (mV)
J	52.3	523	1.24k	15.60	14.32
T	42.8	432	1k	12.77	11.78
K	40.8	408	953Ω	12.17	11.17
S	6.4	63.4	150Ω	1.908	1.766

Typical supply current 50μA

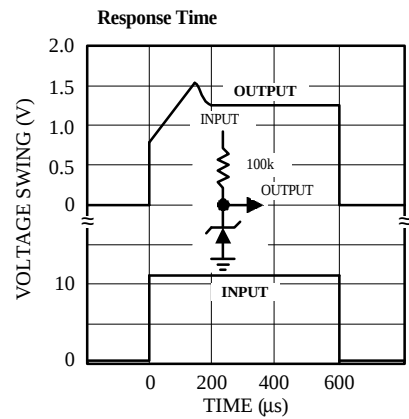
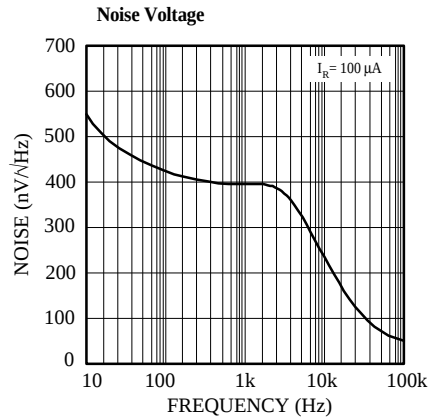
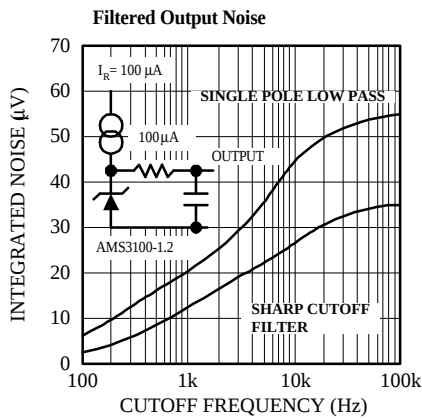
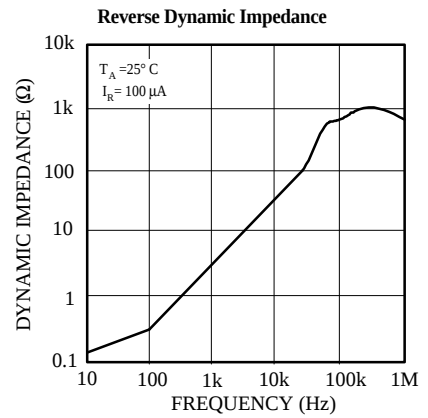
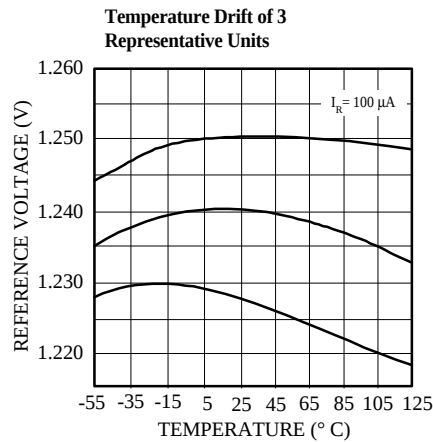
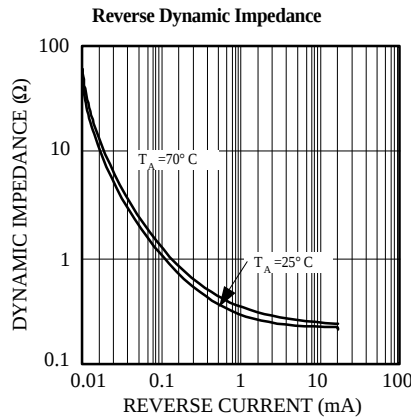
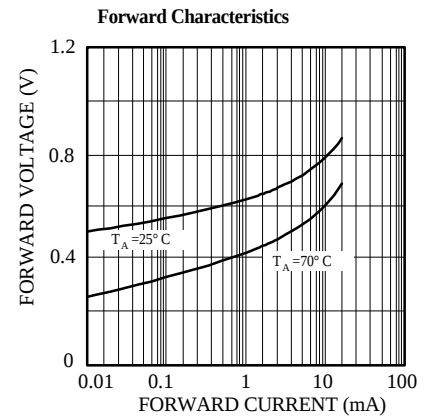
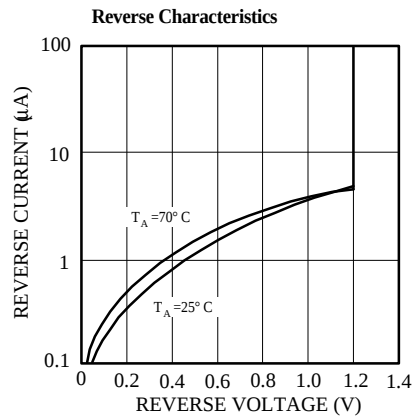
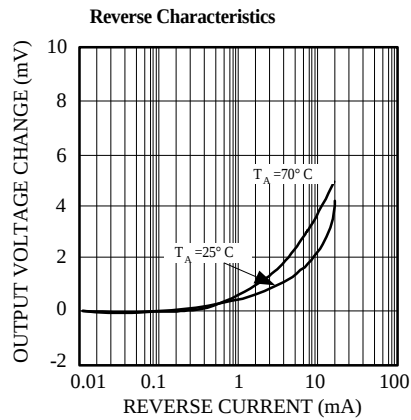
Precision 1μA to 1mA Current Sources



$I_{OUT}^* = 1.23V/R2$

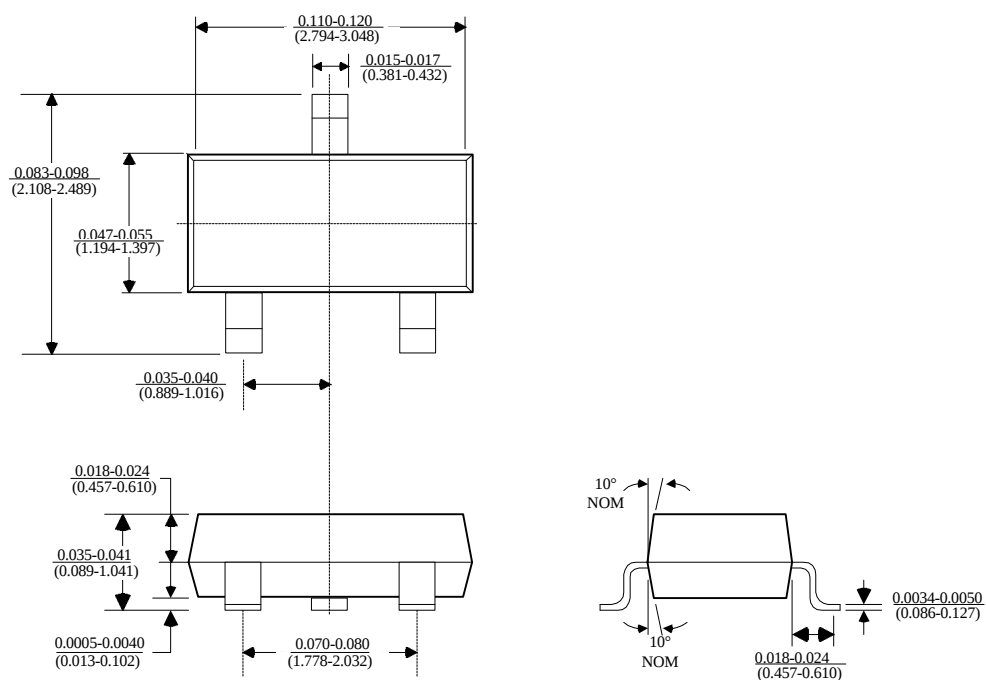


TYPICAL PERFORMANCE CHARACTERISTICS



PACKAGE DIMENSIONS inches (millimeters) unless otherwise noted.

3 LEAD SOT-23 PLASTIC PACKAGE (M)



(SOT-23) AMS DRW# 051991



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- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
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- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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